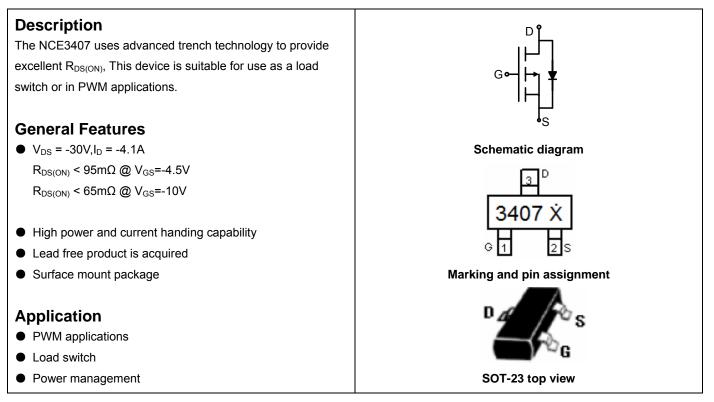


NCE P-Channel Enhancement Mode Power MOSFET



Package Marking and Ordering Information

	0	0			
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
3407 X	NCE3407	SOT-23	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T_A=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	Vds	-30	V	
Gate-Source Voltage	Vgs	±20	V	
Drain Current-Continuous	ID	-4.1	A	
Drain Current-Pulsed (Note 1)	I _{DM}	-20	A	
Maximum Power Dissipation	PD	1.4	W	
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C	

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ ext{ heta}JA}$	90	°C/W

Electrical Characteristics (T_A=25[°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-30	-33	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-24V,V _{GS} =0V	-	-	-1	μA



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Parameter	Symbol	Condition	Min	Тур	Max	Unit
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} ,I _D =-250µA	-1.1	-1.5	-2.1	V
Drain Courses On State Desistence	R _{DS(ON)}	V _{GS} =-10V, I _D =-4.1A	-	48	65	mΩ
Drain-Source On-State Resistance		V _{GS} =-4.5V, I _D =-4A	-	60	95	mΩ
Forward Transconductance	g fs	V _{DS} =-5V,I _D =-1A	-	10	-	S
Dynamic Characteristics (Note4)	·	·				
Input Capacitance	C _{lss}		-	650	-	PF
Output Capacitance	C _{oss}	V _{DS} =-15V,V _{GS} =0V, F=1.0MHz	-	105	-	PF
Reverse Transfer Capacitance	C _{rss}		-	65	-	PF
Switching Characteristics (Note 4)	·	·	•			
Turn-on Delay Time	t _{d(on)}		-	8.5	-	nS
Turn-on Rise Time	tr	V _{DD} =-15V,R _L =3.6Ω	-	4.5	-	nS
Turn-Off Delay Time	t _{d(off)}	V _{GS} =-10V,R _{GEN} =3Ω	-	26	-	nS
Turn-Off Fall Time	t _f		-	12.5	-	nS
Total Gate Charge	Qg		-	12.5	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =-15V,I _D =-4A,V _{GS} =-10V	-	2.8	-	nC
Gate-Drain Charge	Q _{gd}]	-	2.7	-	nC
Drain-Source Diode Characteristics	·					
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-4.1A	-	-	-1.2	V

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- **3.** Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production



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Typical Electrical and Thermal Characteristics

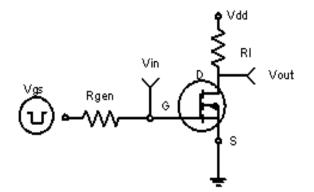
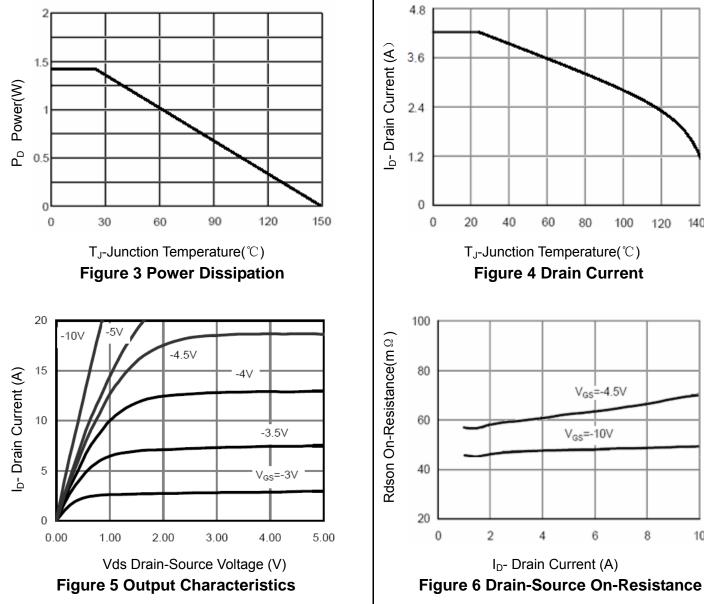


Figure 1:Switching Test Circuit



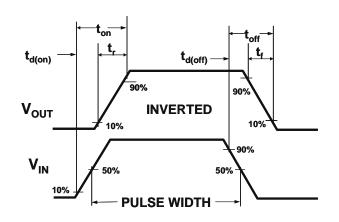
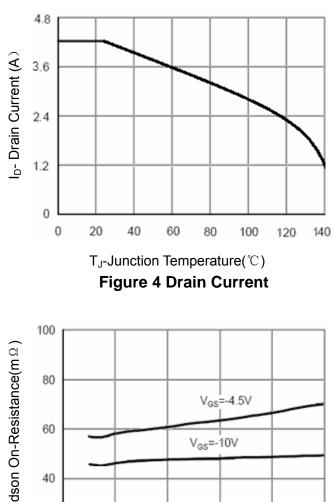


Figure 2:Switching Waveforms



2

4

I_D- Drain Current (A)

6

8

10



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I_D=-4.1A=

150

175

V_{GS}=-4.5V

75

15

100

Ciss

20

25°C

0.6

0.8

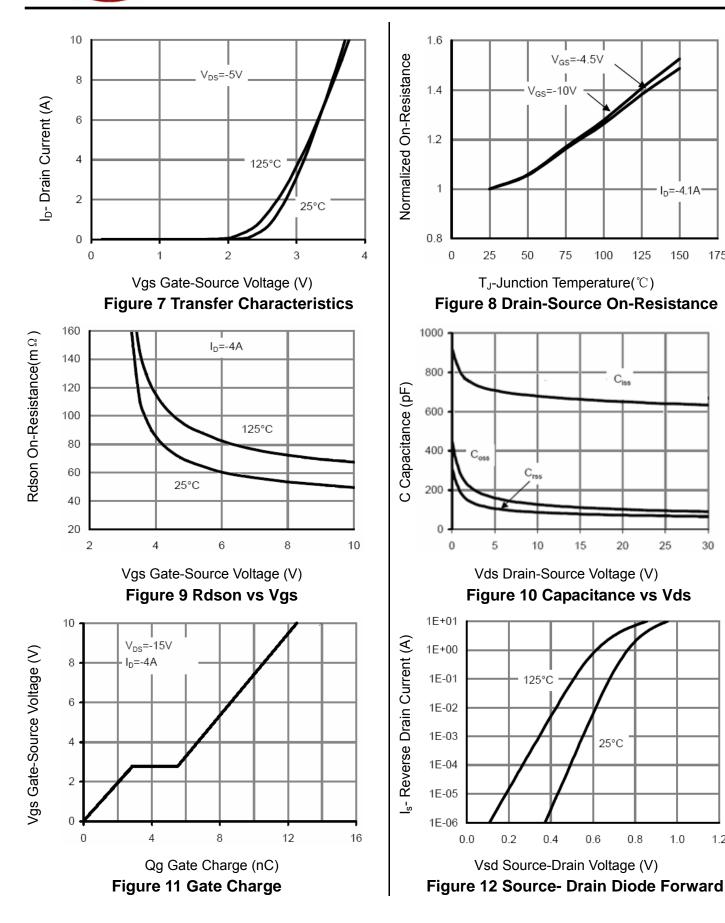
1.0

1.2

25

30

125







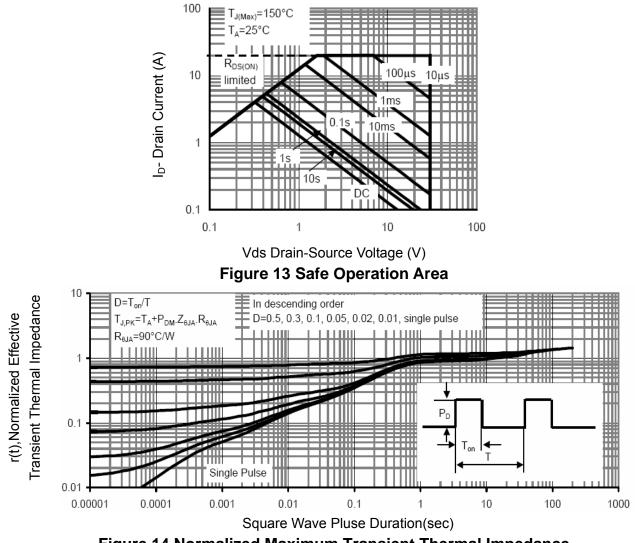
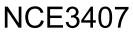
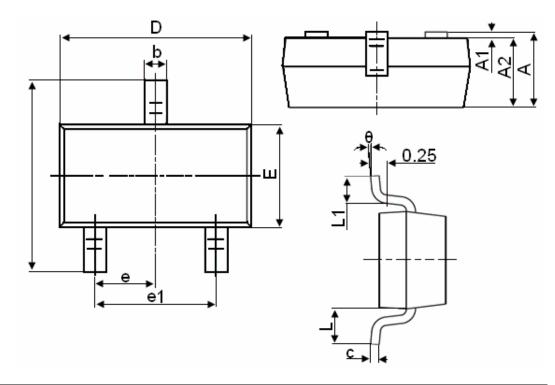


Figure 14 Normalized Maximum Transient Thermal Impedance





SOT-23 Package Information



Symbol		Dimensions in Millimeters		
Symbol	MIN.	MAX.		
A	0.900	1.150		
A1	0.000	0.100		
A2	0.900	1.050		
b	0.300	0.500		
с	0.080	0.150		
D	2.800	3.000		
E	1.200	1.400		
E1	2.250	2.550		
е		0.950TYP		
e1	1.800	2.000		
L		0.550REF		
L1	0.300	0.500		
θ	0°	8°		

Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.







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